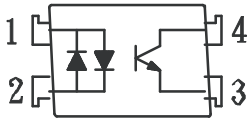


Schematic:



For dimensions and pin-outs, see the last page of this document.

Features:

1. Current transfer ratio (CTR:MIN.50% at $I_F=5\text{mA}$ $V_{CE}=0.5\text{V}$)
2. High isolation voltage between input and output (Viso:5300Vrms).
3. Compact dual-in-line package.
4. Ac input.

Ordering:

Suffix to Standard Part Number

- V = VDE Compliant
- G = 10mm Lead Spread
- S = Surface Mount Lead-form
- T = Tape & Reel

Superior OPTO Part Number:

OPTO440

Absolute Maximum Ratings:

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	± 50	mA
	Peak forward current	I_{FM}	± 1	A
	Power dissipation	P_D	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
	Total power dissipation	P_{tot}	200	mW
	Isolation voltage 1 minute	Viso	5300	Vrms
	Operating temperature	T_{opr}	-55 to +100	°C
	Storage temperature	T_{stg}	-55 to +125	°C
	Soldering temperature 10 second	T_{sol}	260	°C

Electrical Characteristics:

(Ta=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F = \pm 20\text{mA}$	—	1.2	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM} = \pm 0.5\text{A}$	—	—	3.5	V
	Terminal capacitance	C_t	$V=0, f=1\text{kHz}$	—	30	—	pF
Output	Collector dark current	I_{CEO}	$V_{CE} = 20\text{V}, I_F = 0$	—	—	0.1	uA
Transfer characteristics	Current transfer ratio	CTR	$I_F = 5\text{mA}, V_{CE} = 0.5\text{V}$	50	—	—	%
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F = 5\text{mA}, I_C = 1\text{mA}$	—	—	0.4	V
	Isolation resistance	Riso	DC500V	5×10^{10}	10^{11}	—	ohm
	Floating capacitance	C_f	$V=0, f=1\text{MHz}$	—	0.6	1.0	pF
	Cut-off frequency	f_c	$V_{CC} = 5\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	80	—	kHz
	Response time (Rise)	t_r	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	5	20	us
	Response time (Fall)	t_f		—	4	20	us

CTR Selections are Available

Fig.1 Current Transfer Ratio vs. Forward Current

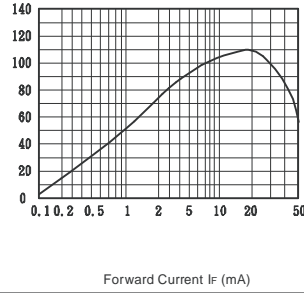


Fig.2 Collector Power Dissipation vs. Ambient Temperature

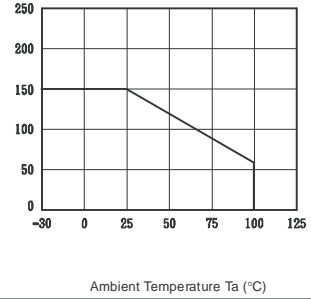


Fig.3 Collector Dark Current vs. Ambient Temperature

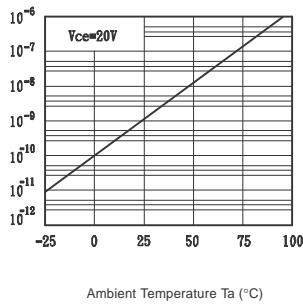


Fig.4 Forward Current vs. Ambient Temperature

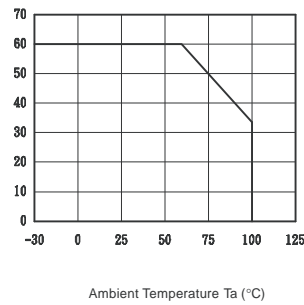


Fig.5 Forward Current vs. Forward Voltage

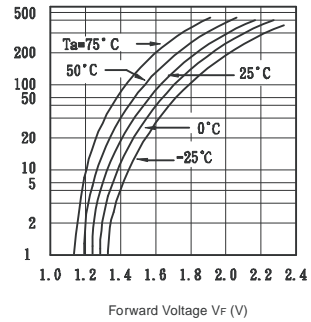


Fig.6 Collector Current vs. Collector-emitter Voltage

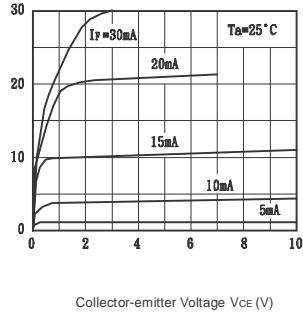


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

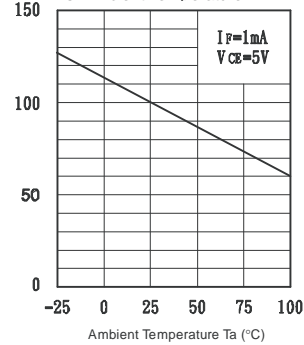


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

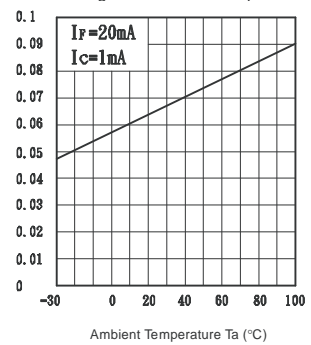


Fig.9 Collector-emitter Saturation Voltage vs. Forward Current

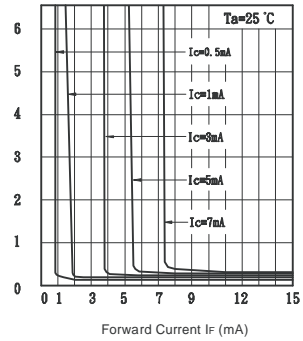


Fig.10 Response Time vs. Load Resistance

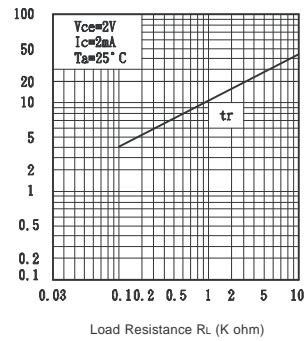


Fig.11 Response Time vs. Load Resistance

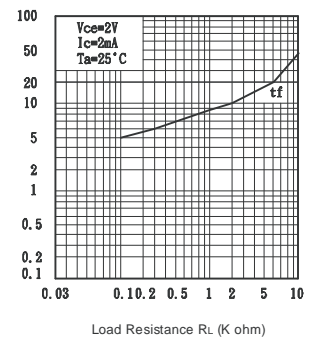


Fig.1 : 4-pin DIP type

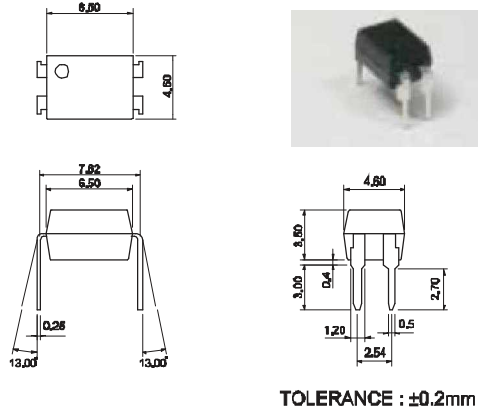


Fig.2 : 4-pin SMD type

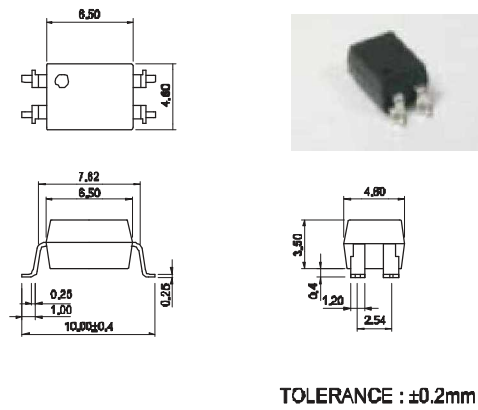


Fig.3 : 4-pin G type

